



Winbond Electronics Corporation

W947D6HBHX5E

Številka dela:

W947D6HBHX5E

Proizvajalec / znamka:

Winbond Electronics Corporation

Opis izdelka

IC DRAM 128M PARALLEL 60VFBGA

Podatkovni listi:

 W947D6HBHX5E.pdf

Status RoHS

 Skladen brez svinca / RoHS

Stanje zalog

28005 pcs stock

Iz ladje

Hong Kong


Način pošiljanja

DHL/Fedex/TNT/UPS/EMS

[ZAHTEVA ZA PONUDBO](#)

Slika je lahko reprezentativna. Oglejte si specifikacije za podrobnosti izdelka.











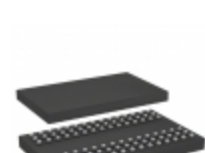
Specifikacije W947D6HBHX5E

ŠTEVILKA DELA	W947D6HBHX5E
PROIZVAJALEC	Winbond Electronics Corporation
OPIS	IC DRAM 128M PARALLEL 60VFBGA
STATUS SVOBODNEGA STATUSA / ROHS	Skladen brez svinca / RoHS
KOLIČINA NA VOLJO	28005 pcs
PODATKOVNI LIST	 W947D6HBHX5E.pdf
ČAS CIKLA PISANJA -	15ns
NAPETOST - OSKRBA	1.7 V ~ 1.95 V
TEHNOLOGIJA	SDRAM - Mobile LPDDR
PAKET NAPRAVE ZA DOBAVITELJA	60-VFBGA (8x9)
SERIJA	-
PAKIRANJE	Tray
PAKET / PRIMER	60-TFBGA
DELOVNA TEMPERATURA	-25°C ~ 85°C (TC)
TIP MONTAŽE	Surface Mount
RAVEN OBČUTLJIVOSTI NA VLAGO (MSL)	3 (168 Hours)
VRSTA POMNILNIKA	Volatile
VELIKOST POMNILNIKA	128Mb (8M x 16)
POMNILNIŠKI VMESNIK	Parallel
FORMAT POMNILNIKA	DRAM
STATUS SVOBODNEGA STATUSA / ROHS	Lead free / RoHS Compliant
NATANČEN OPIS	SDRAM - Mobile LPDDR Memory IC 128Mb (8M x 16) Parallel 200MHz 5ns 60-VFBGA (8x9)
FREKVENCA URE	200MHz
ČAS DOSTOPA	5ns

Sorodne oznake

Winbond Electronics Corporation W947D6HBHX5E	W947D6HBHX5E Distributer	W947D6HBHX5E Dobavitelj
Cena W947D6HBHX5E	Slike W947D6HBHX5E	Slika W947D6HBHX5E
W947D6HBHX5E PDF Datasheet	W947D6HBHX5E Prenesi podatkovni list	W947D6HBHX5E Datasheet
Zaloga W947D6HBHX5E	Kupi W947D6HBHX5E	Kupi Winbond Electronics Corporation W947D6HBHX5E
Winbond Electronics Corporation W947D6HBHX5E	Winbond Electronics Corporation Dobavitelj	Distributer Winbond Electronics Corporation
Winbond Electronics Corporation W947D6HBHX5E	Winbond W947D6HBHX5E	Winbond Electronics W947D6HBHX5E

Podobni izdelki

 <p>W947D2HBX6E TR Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 90VFBGA Na zalogi: 39766 pcs</p> <p>RFQ</p>	 <p>W947D6HBHX5I Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 60VFBGA Na zalogi: 25230 pcs</p> <p>RFQ</p>
 <p>W948D2FBX5E Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 256M PARALLEL 90VFBGA Na zalogi: 24886 pcs</p> <p>RFQ</p>	 <p>W947D2HBX5E TR Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 90VFBGA Na zalogi: 32527 pcs</p> <p>RFQ</p>
 <p>W947D2HBX5I TR Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 90VFBGA Na zalogi: 36049 pcs</p> <p>RFQ</p>	 <p>W947D2HBX5I Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 90VFBGA Na zalogi: 33675 pcs</p> <p>RFQ</p>
 <p>W947D6HBX5E TR Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 60VFBGA Na zalogi: 21956 pcs</p> <p>RFQ</p>	 <p>W947D2HBX5E Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 90VFBGA Na zalogi: 35051 pcs</p> <p>RFQ</p>
 <p>W947D6HBX6E Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 60VFBGA Na zalogi: 31376 pcs</p> <p>RFQ</p>	 <p>W947D6HBX5I TR Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 60VFBGA Na zalogi: 39512 pcs</p> <p>RFQ</p>
 <p>W947D6HBX6E TR Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 60VFBGA Na zalogi: 39916 pcs</p> <p>RFQ</p>	 <p>W947D2HBX6E Proizvajalci: Winbond Electronics Corporation Opis: IC DRAM 128M PARALLEL 90VFBGA Na zalogi: 28336 pcs</p> <p>RFQ</p>